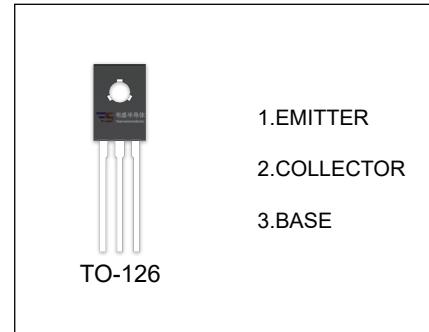


3CA772 TRANSISTOR (PNP)

FEATURES

- High Current
- Low Voltage



ORDERING INFORMATION

Part Number	Package	Packing Method	Pack Quantity
3CA772	TO-126	Bulk	200pcs/Bag
3CA772-TU	TO-126	Tube	60pcs/Tube

MAXIMUM RATINGS ($T_a=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	-40	V
V_{CEO}	Collector-Emitter Voltage	-30	V
V_{EBO}	Emitter-Base Voltage	-6	V
I_C	Collector Current	-3	A
P_c	Collector Power Dissipation	1.25	W
$R_{\theta JA}$	Thermal Resistance From Junction To Ambient	100	°C/W
T_J, T_{stg}	Operation Junction and Storage Temperature Range	-55~+150	°C

T_a=25 °C unless otherwise specified

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _C =-100μA,I _E =0	-40			V
Collector-emitter breakdown voltage	V _{(BR)CEO}	I _C =-10mA,I _B =0	-30			V
Emitter-base breakdown voltage	V _{(BR)EBO}	I _E =-100μA,I _C =0	-6			V
Collector cut-off current	I _{CBO}	V _{CB} =-40V,I _E =0			-1	μA
Collector cut-off current	I _{CEO}	V _{CE} =-30V,I _B =0			-10	μA
Emitter cut-off current	I _{EBO}	V _{EB} =-6V,I _C =0			-1	μA
DC current gain	h _{FE}	V _{CE} =-2V,I _C =-1A	60		400	
Collector-emitter saturation voltage	V _{CE(sat)}	I _C =-2A,I _B =-0.2A			-0.5	V
Base-emitter saturation voltage	V _{BE(sat)}	I _C =-2A,I _B =-0.2A			-1.5	V
Transition frequency	f _T	V _{CE} =-5V,I _C =-0.1A,f=10MHz	50			MHz

CLASSIFICATION OF h_{FE}

RANK	R	O	Y	GR
RANGE	60-120	100-200	160-320	200-400